

WAT100TBS16

SCR Module Rev.01 - 15 November 2024

Product data sheet

1. General description

Planar passivated Silicon Controlled Rectifier (SCR) module in WeEnTOP-B for use in applications requiring high blocking voltage capability, high inrush current capability and high thermal cycling performance.

2. Features and benefits

- · Planar passivated thyristor chips for voltage ruggedness and reliability
- Top-side cooling
- Compact design
- One screw mounting
- Heat transfer and isolation through direct copper bonded aluminum oxide ceramic (DBC)
- Package is RoHS compliant

3. Applications

- Soft starters
- UPS
- Temperature control
- Lighting control
- AC power control

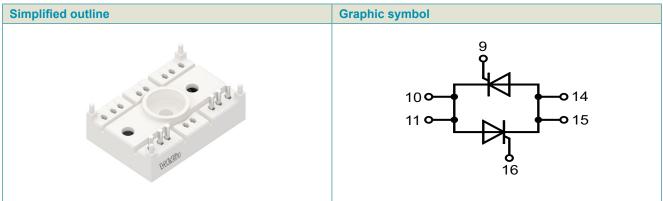
4. Quick reference data

Table 4. Quiak reference date

Symbol	Parameter	Conditions	Notes		Values		Unit
Absolute	maximum rating						
V_{DRM}	repetitive peak forward voltage				1600		V
V_{RRM}	repetitive peak reverse voltage				1600		V
I _{T(RMS)}	RMS on-state current	half sine wave			101		А
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; t_p = 10 ms		1500			А
		half sine wave; $T_{j(init)}$ = 125 °C; t_p = 10 ms			1350		А
		half sine wave; $T_{j(init)}$ = 25 °C; t_p = 8.3 ms			1650		А
		half sine wave; $T_{j(init)}$ = 125 °C; t_p = 8.3 ms		1485			А
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static ch	aracteristics				Ì		
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C		30	-	100	mA
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C		-	-	1.50	V
V _T	on-state voltage	I _T = 200 A; T _i = 25 °C		-	-	1.70	V

5. Pinning information





6. Ordering information

Table 3. Ordering information

Type number	Package Name	Orderable part number	•	Small packing quantity	•	Package issue date
WAT100TBS16	WeEnTOP-B	WAT100TBS16T	EPE	30	WeEnTOP-BPAT-A	05-Nov-2024

7. Marking

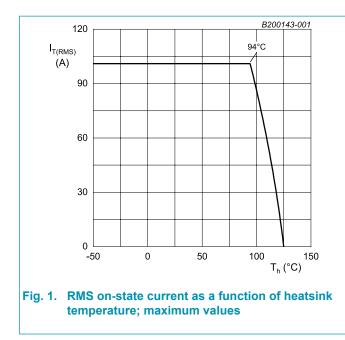
Table 4. Marking codes	
Type number	Marking codes
WAT100TBS16	WAT100TBS16

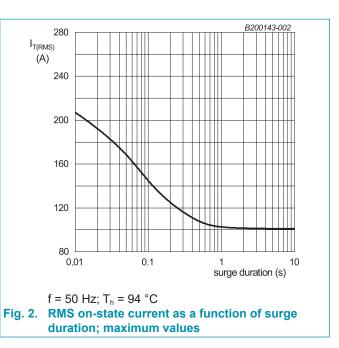
8. Limiting values

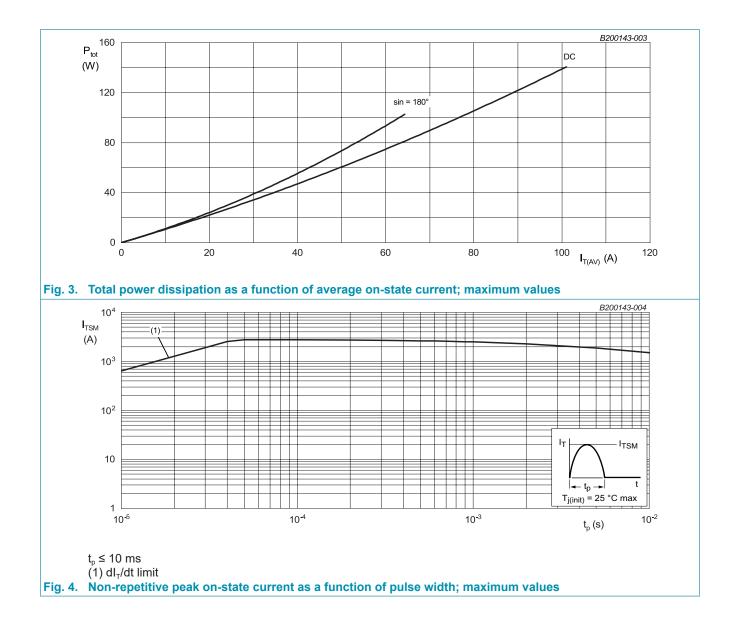
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V _{DRM}	repetitive peak forward voltage			1600	V
V _{RRM}	repetitive peak reverse voltage			1600	V
I _{T(RMS)}	RMS on-state current	half sine wave		101	А
I _{TSM}	non-repetitive peak onstate	half sine wave; $T_{j(init)}$ = 25 °C; t_p = 10 ms		1500	А
	current	half sine wave; $T_{j(init)}$ = 125 °C; t_p = 10 ms		1350	А
		half sine wave; $T_{j(init)}$ = 25 °C; t_p = 8.3 ms		1650	А
		half sine wave; $T_{j(init)}$ = 125 °C; t_p = 8.3 ms		1485	А
l ² t	l ² t for fusing	t _p = 10 ms; sine-wave pulse		11.25	kA²s
dl _T /dt	rate of rise of on-state current	I _G = 200 mA; T _j = 125 °C		200	A/µs
I _{GM}	peak gate current			10	А
V _{RGM}	peak reverse gate voltage			5	V
P _{GM}	peak gate power			20	W
$P_{G(AV)}$	average gate power	over any 20 ms period		0.5	W
T _{vj}	virtual junction temperature			-40 to 125	°C
T _{op}	operation temperature			-40 to 125	°C
T _{stg}	storage temperature			-40 to 125	°C



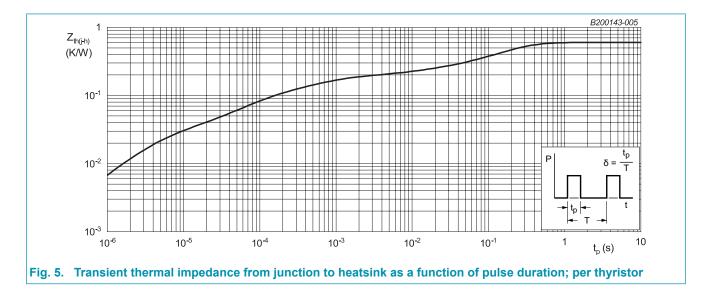




9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
ui(j-ii)	thermal resistance from	per thyristor		-	-	0.6	K/W
	junction to heatsink	per module		-	-	0.3	K/W



10. Package characteristics

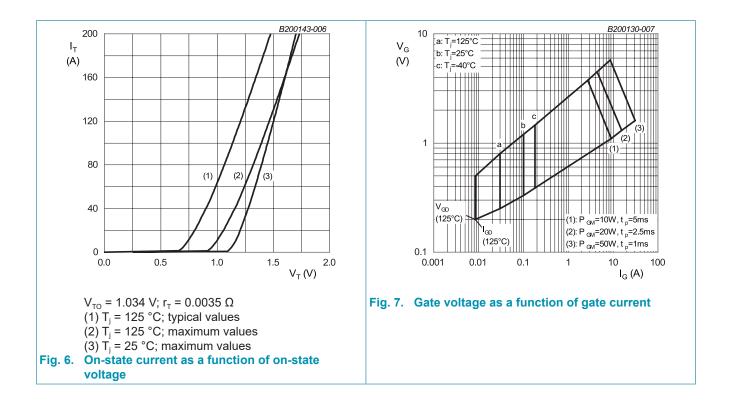
Table 7. Isolation characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
V _{isol}	isolation voltage	50/60 Hz; RMS; I _{ISOL} ≤ 1 mA; t = 1 second; AC		-	-	3600	V
		50/60 Hz; RMS; $I_{ISOL} \le 1 \text{ mA}$; t = 1 minute; AC		-	-	2500	V

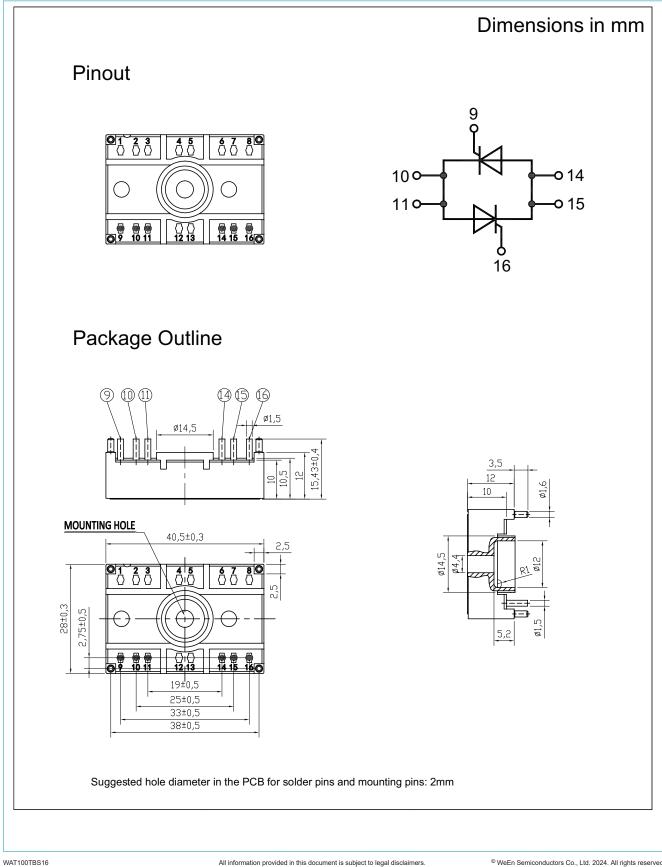
11. Characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static cha	aracteristics						
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C		30	-	100	mA
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C		-	-	1.50	V
		$V_{\rm D}$ = 2/3 $V_{\rm DRM}$; $I_{\rm T}$ = 0.1 A; $T_{\rm j}$ = 125 °C		0.25	-	-	V
I _{GD}	gate non-trigger current	T _j = 125 °C		-	-	8.5	mA
V_{GD}	gate non-trigger voltage	T _j = 125 °C		-	-	0.2	V
I _L	latching current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C		-	-	300	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C		-	-	200	mA
V _T	on-state voltage	I _T = 200 A; T _j = 25 °C		-	-	1.70	V
V _{TO}	threshold voltage	T _j = 125 °C		-	-	1.0	V
r _T	slope resistance	T _j = 125 °C		-	-	3.5	mΩ
I _D	off-state current	V _D = 1600 V; T _j = 25 °C		-	-	100	μA
		V _D = 1600 V; T _j = 125 °C		-	-	15	mA
I _R	reverse current	V _R = 1600 V; T _j = 25 °C		-	-	100	μA
		V _R = 1600 V; T _j = 125 °C		-	-	15	mA
Dynamic	characteristics						_
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 1072 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit		1500	-	-	V/µs
t _{gt}	gate-controlled turn-on time	$I_{TM} = 40 \text{ A}; V_D = 800 \text{ V}; I_G = 100 \text{ mA};$ $(dI_G/dt)_M = 1 \text{ A}/\mu\text{s}; T_j = 25 \text{ °C}$		-	2	-	μs
t _q	commutated turn-off time	$I_{TM} = 2 \text{ A}; t_p = 50 \mu\text{s}; \text{dV/dt} = 5 \text{V/}\mu\text{s}; \text{dI/dt} = 30 \text{A/}\mu\text{s}; \text{T}_j = 25 ^\circ\text{C}$		-	150	-	μs

WAT100TBS16 SCR Module



12. Package outline



Product data sheet

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WAT100TBS16 SCR Module

13. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

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